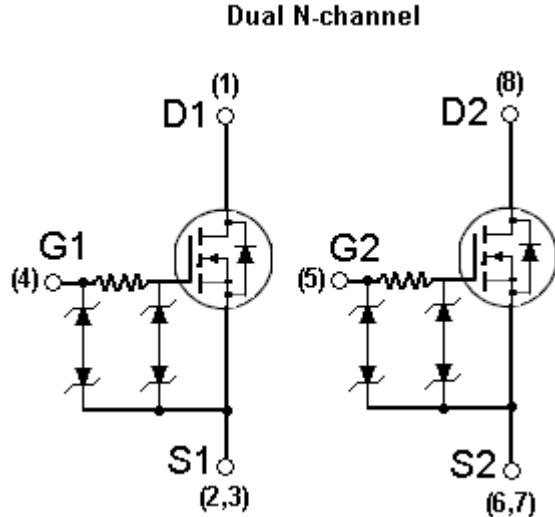




# TSM6968SD

## 20V Dual N-Channel MOSFET w/ESD Protected

 <p><b>TSSOP-8</b></p> <p>Pin assignment:</p> <ol style="list-style-type: none"> <li>1. Drain 1</li> <li>2. Source 1</li> <li>3. Source 1</li> <li>4. Gate 1</li> <li>5. Gate 2</li> <li>6. Source 2</li> <li>7. Source 2</li> <li>8. Drain 2</li> </ol>	<p><b>V<sub>DS</sub> = 20V</b></p> <p><b>R<sub>Ds(on)</sub>, V<sub>GS</sub> @ 4.5V, I<sub>DS</sub> @ 6.5A = 25mΩ</b></p> <p><b>R<sub>Ds(on)</sub>, V<sub>GS</sub> @ 2.5V, I<sub>DS</sub> @ 5.5A = 35mΩ</b></p>						
<p><b>Features</b></p> <ul style="list-style-type: none"> <li>◊ Advanced trench process technology</li> <li>◊ High density cell design for ultra low on-resistance</li> <li>◊ Excellent thermal and electrical capabilities</li> <li>◊ Specially designed for Li-ion battery packs.</li> <li>◊ Battery switch application</li> </ul>	<p><b>Block Diagram</b></p> <p style="text-align: center;"><b>Dual N-channel</b></p> 						
<p><b>Ordering Information</b></p> <table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th style="text-align: left; padding: 2px;">Part No.</th> <th style="text-align: left; padding: 2px;">Packing</th> <th style="text-align: left; padding: 2px;">Package</th> </tr> </thead> <tbody> <tr> <td style="text-align: left; padding: 2px;">TSM6968SDCA</td> <td style="text-align: left; padding: 2px;">Tape &amp; Reel 3,000/per reel</td> <td style="text-align: left; padding: 2px;">TSSOP-8</td> </tr> </tbody> </table>	Part No.	Packing	Package	TSM6968SDCA	Tape & Reel 3,000/per reel	TSSOP-8	
Part No.	Packing	Package					
TSM6968SDCA	Tape & Reel 3,000/per reel	TSSOP-8					

### Absolute Maximum Rating (Ta = 25 °C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	20V	V
Gate-Source Voltage	V <sub>GS</sub>	± 12	V
Continuous Drain Current, V <sub>GS</sub> @ 4.5V.	I <sub>D</sub>	6.5	A
Pulsed Drain Current, V <sub>GS</sub> @ 4.5V	I <sub>DM</sub>	30	A
Maximum Power Dissipation	P <sub>D</sub>	1.5	W
		0.96	
Operating Junction Temperature	T <sub>J</sub>	+150	°C
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to +150	°C

### Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Foot (Drain) Thermal Resistance	R <sub>θjf</sub>	35	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	R <sub>θja</sub>	83	°C/W

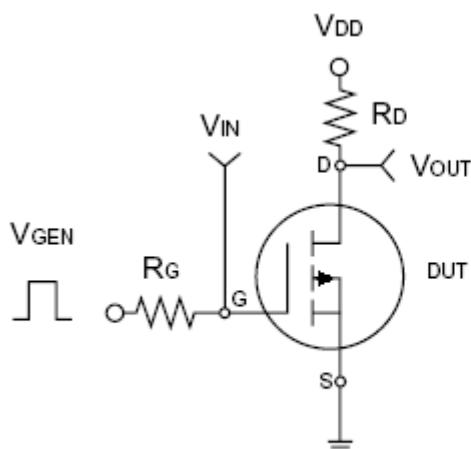
Note: Surface mounted on FR4 board t<=10sec.

## Electrical Characteristics

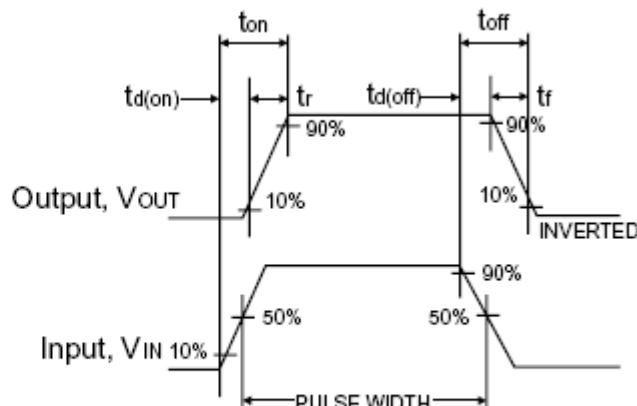
Rate  $I_D = 6.5A$ , ( $T_a = 25^\circ C$  unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	$BV_{DSS}$	20	--	--	V
Drain-Source On-State Resistance	$V_{GS} = 4.5V, I_D = 6.5A$	$R_{DS(ON)}$	--	18	25	
Drain-Source On-State Resistance	$V_{GS} = 2.5V, I_D = 5.5A$	$R_{DS(ON)}$	--	28	35	$m\Omega$
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	$V_{GS(TH)}$	0.5	0.85	--	V
Zero Gate Voltage Drain Current	$V_{DS} = 20V, V_{GS} = 0V$	$I_{DSS}$	--	--	1.0	$\mu A$
Gate Body Leakage	$V_{GS} = \pm 12V, V_{DS} = 0V$	$I_{GSS}$	--	--	$\pm 10$	$\mu A$
On-State Drain Current	$V_{GS} = 4.5V, V_{DS} \geq 5V$	$I_{D(ON)}$	30	--	--	A
Forward Transconductance	$V_{DS} = 10V, I_D = 6.5A$	$g_{fs}$	--	30	--	S
<b>Dynamic</b>						
Total Gate Charge	$V_{DS} = 10V, I_D = 6.5A,$ $V_{GS} = 4.5V$	$Q_g$	--	15.5	30	
Gate-Source Charge		$Q_{gs}$	--	2	--	nC
Gate-Drain Charge		$Q_{gd}$	--	3.5	--	
Turn-On Delay Time	$V_{DD} = 10V, R_L = 10\Omega,$ $I_D = 1A, V_{GEN} = 4.5V,$ $R_G = 6\Omega$	$t_{d(on)}$	--	75	100	
Turn-On Rise Time		$t_r$	--	125	150	nS
Turn-Off Delay Time		$t_{d(off)}$	--	600	720	
Turn-Off Fall Time		$t_f$	--	300	360	
Input Capacitance	$V_{DS} = 10V, V_{GS} = 0V,$ $f = 1.0MHz$	$C_{iss}$	--	1336	--	
Output Capacitance		$C_{oss}$	--	220	--	pF
Reverse Transfer Capacitance		$C_{rss}$	--	130	--	
<b>Source-Drain Diode</b>						
Max. Diode Forward Current		$I_S$	--	--	1.5	A
Diode Forward Voltage	$I_S = 1.5A, V_{GS} = 0V$	$V_{SD}$	--	0.6	1.2	V

Note : pulse test: pulse width  $\leq 300\mu S$ , duty cycle  $\leq 2\%$

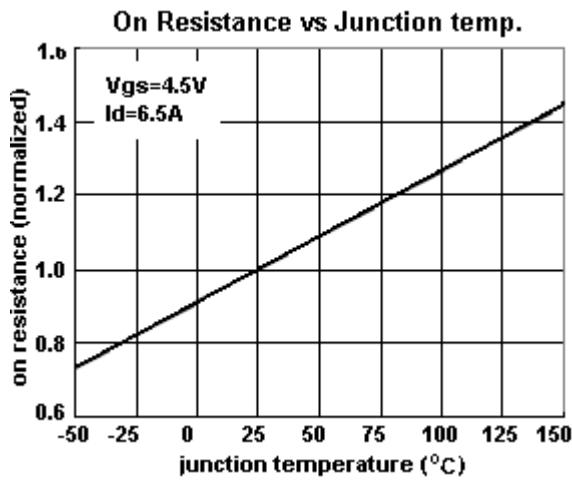
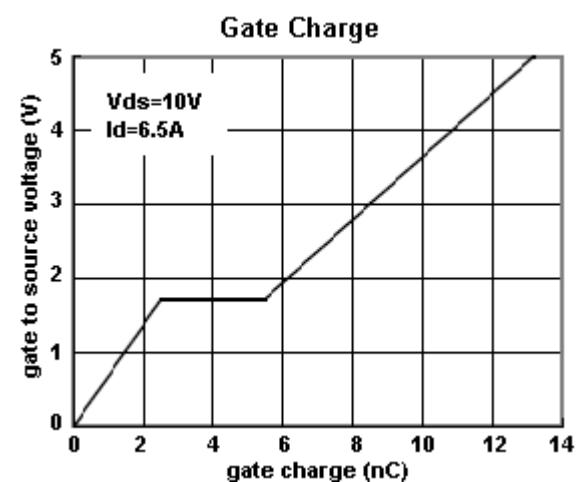
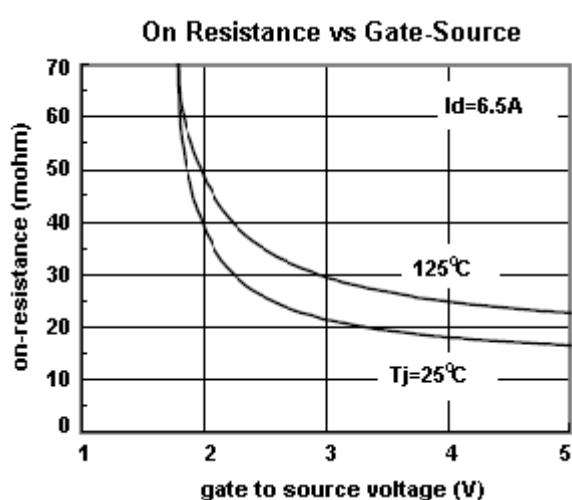
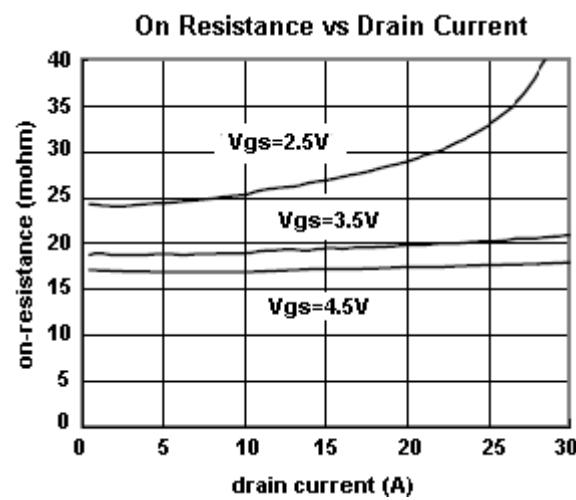
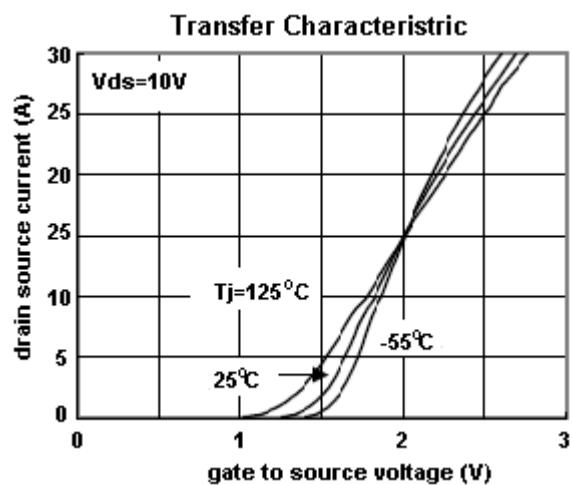
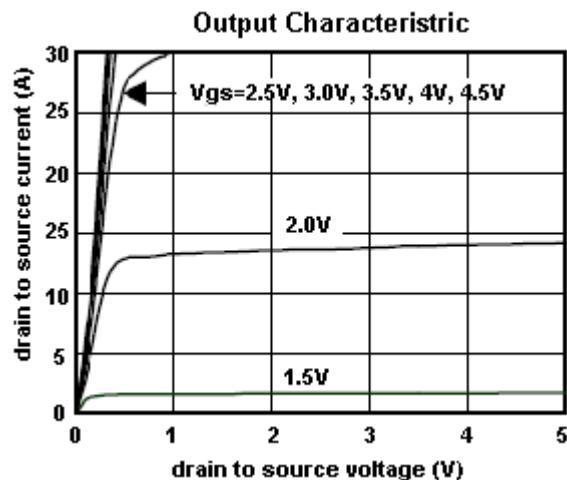


Switching Test Circuit

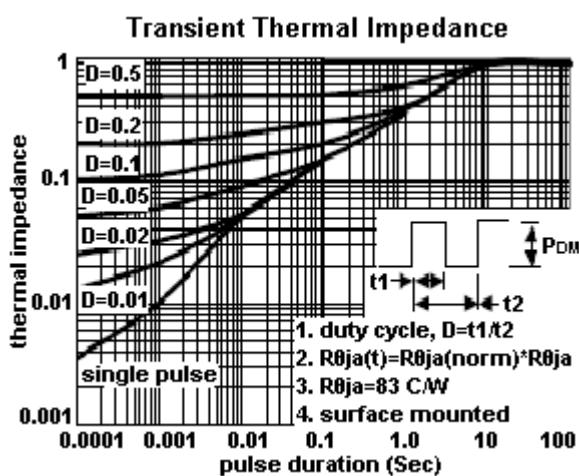
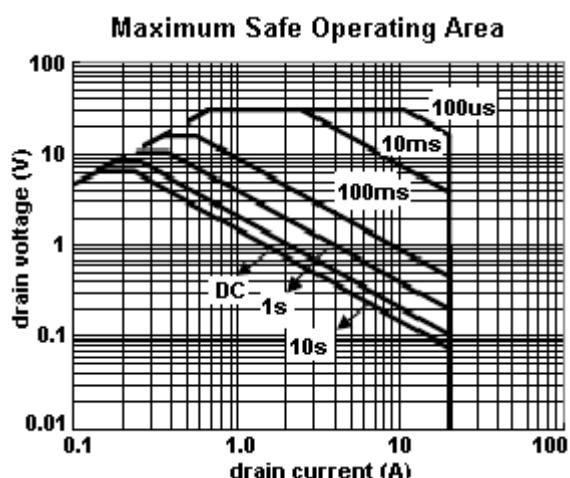
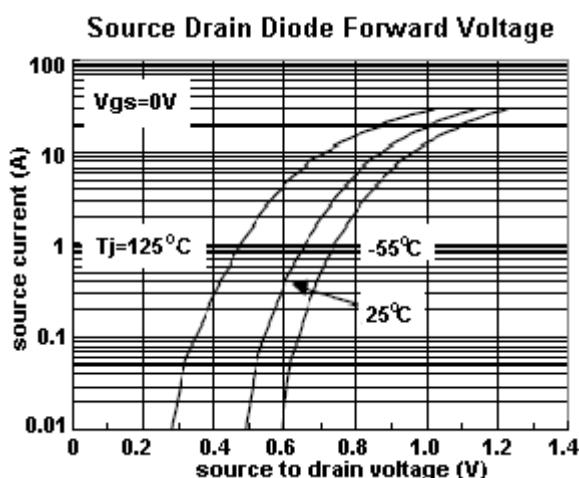
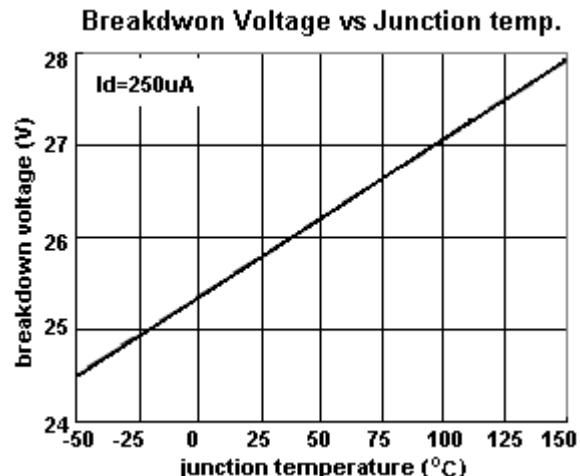
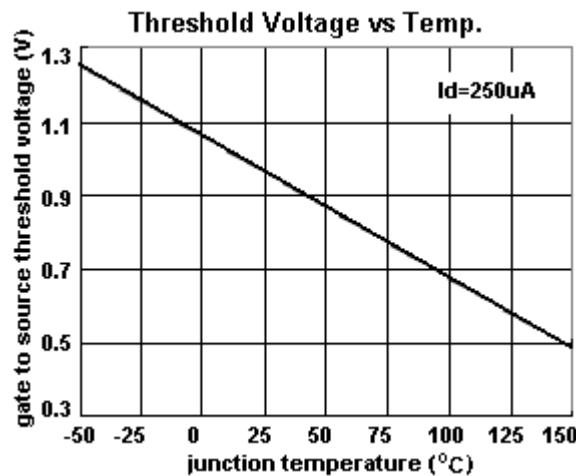


Switchin Waveforms

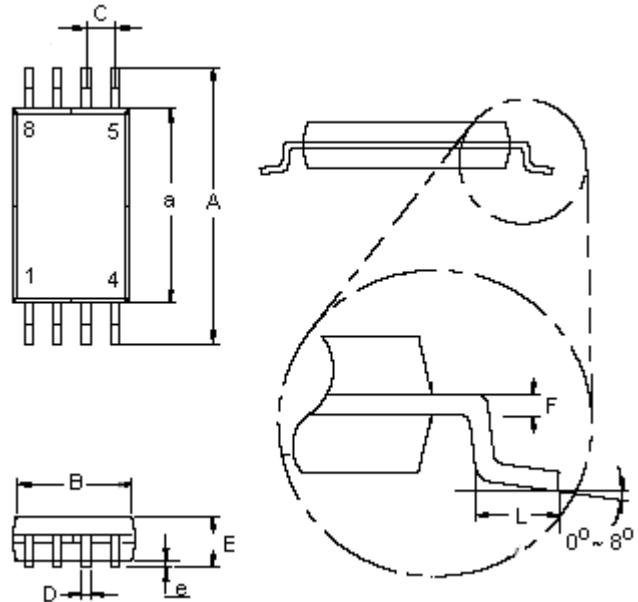
### Typical Characteristics Curve ( $T_a = 25^\circ\text{C}$ unless otherwise noted)



## Electrical Characteristics Curve (continued)



## TSSOP-8 Mechanical Drawing



TSSOP-8 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	6.20	6.60	0.244	0.260
a	4.30	4.50	0.170	0.177
B	2.90	3.10	0.114	0.122
C	0.65 (typ)		0.025 (typ)	
D	0.25	0.30	0.010	0.019
E	1.05	1.20	0.041	0.049
e	0.05	0.15	0.002	0.009
F	0.127		0.005	
L	0.50	0.70	0.020	0.028